2SD0874, 2SD0874A (2SD874, 2SD874A)

Silicon NPN epitaxial planar type

For low-frequency power amplification

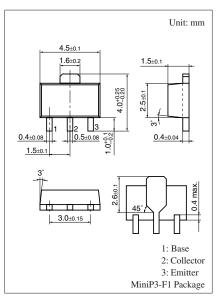
Complementary to 2SB0766 (2SB766) and 2SB0766A (2SB766A)

Features

- \bullet Large collector power dissipation $P_{\rm C}$
- \bullet Low collector-emitter saturation voltage $V_{\mbox{CE(sat)}}$
- Mini power type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing

nol Rating 0 30 60 0 0 25	Unit V V
60 0 25	
25	V
, <u> </u>	V
50	_
50	
5 5	V
1	А
1.5	А
1	W
150	°C
	0 °C
	1

Absolute Maximum Ratings $T_a = 25^{\circ}C$



Marking Symbol:

• 2SD0874: Z

• 2SD0874A: Y

Note) *: Printed circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage	2SD0874	V _{CBO}	$I_{\rm C} = 10 \ \mu A, \ I_{\rm E} = 0$	30			V
(Emitter open)	2SD0874A			60			
Collector-emitter voltage	2SD0874	V _{CEO}	$I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$	25			V
(Base open)	2SD0874A			50			
Emitter-base voltage (Collector open)		V _{EBO}	$I_E = 10 \ \mu A, \ I_C = 0$	5			V
Collector-base cutoff current (Emitter open)		I _{CBO}	$V_{CB} = 20 V, I_E = 0$			0.1	μΑ
Forward current transfer ratio *1		h _{FE1} *2	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 500 \text{ mA}$	85		340	
		h _{FE2}	$V_{CE} = 5 V, I_C = 1 A$	50			
Collector-emitter saturation voltage *1		V _{CE(sat)}	$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 50 \text{ mA}$		0.2	0.4	V
Base-emitter saturation voltage *1		V _{BE(sat)}	$I_{C} = 500 \text{ mA}, I_{B} = 50 \text{ mA}$		0.85	1.2	V
Transition frequency		f _T	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Collector output capacitance		C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$			20	pF
(Common base, input open circuited)							

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

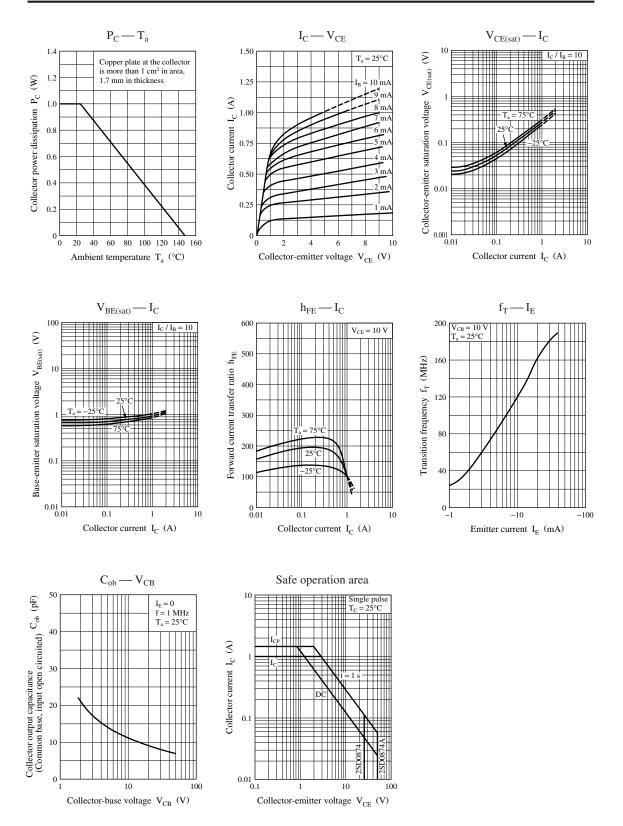
2. *1: Pulse measurement

*2: Rank classification

Rank	Q	R	S	
$h_{\rm FE1}$	85 to 170	120 to 240	170 to 340	

Note) The part numbers in the parenthesis show conventional part number.

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